SCS206AG

SiC Schottky Barrier Diode
Datasheet

| $\mathrm{V}_{\mathrm{R}}$ | 650 V |
| :---: | :---: |
| $\mathrm{I}_{\mathrm{F}}$ | 6 A |
| $\mathrm{Q}_{\mathrm{C}}$ | 9 nC |

## - Features

1) Shorter recovery time
2) Reduced temperature dependence
3) High-speed switching possible

## - Construction

Silicon carbide epitaxial planer type
-Outline


## - Inner circuit


$\bullet$ Packaging specifications

| Type | Packaging | Tube |
| :--- | :--- | :---: |
|  | Reel size $(\mathrm{mm})$ | - |
|  | Tape width $(\mathrm{mm})$ | - |
|  | Basic ordering unit $(\mathrm{pcs})$ | 50 |
|  | Packing code | C |
|  | Marking | SCS206AG |

$\bullet$ Absolute maximum ratings $\left(\mathrm{Tj}=25^{\circ} \mathrm{C}\right)$

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Reverse voltage (repetitive peak) | $\mathrm{V}_{\mathrm{RM}}$ | 650 | V |
| Reverse voltage (DC) | $V_{R}$ | 650 | V |
| Continuous forward current | $I_{\text {F }}$ | $6^{* 1}$ | A |
| Surge no repetitive forward current | $\mathrm{I}_{\text {FSM }}$ | $24^{*}$ | A |
|  |  | $91^{*}$ | A |
|  |  | $18^{*}$ | A |
| Repetitive peak forward current | $\mathrm{I}_{\text {FRM }}$ | $26^{*}{ }^{5}$ | A |
| Total power disspation | $\mathrm{P}_{\mathrm{D}}$ | $51^{*}{ }^{6}$ | W |
| Junction temperature | Tj | 175 | ${ }^{\circ} \mathrm{C}$ |
| Range of storage temperature | Tstg | -55 to +175 | ${ }^{\circ} \mathrm{C}$ |

*1 $\mathrm{Tc}=138^{\circ} \mathrm{C}$ *2 $\mathrm{PW}=8.3 \mathrm{~ms}$ sinusoidal, $\mathrm{Tj}=25^{\circ} \mathrm{C}$ *3 $\mathrm{PW}=10 \mu \mathrm{~s}$ square, $\mathrm{Tj}=25^{\circ} \mathrm{C}$
*4 PW $=8.3 \mathrm{~ms}$ sinusoidal, $\mathrm{Tj}=150^{\circ} \mathrm{C} * 5 \mathrm{Tc}=100^{\circ} \mathrm{C}, \mathrm{Tj}=150^{\circ} \mathrm{C}$, Duty cycle $=10 \%{ }^{*} 6 \mathrm{Tc}=25^{\circ} \mathrm{C}$
$\bullet$ Electrical characteristics ( $\mathrm{Tj}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Conditions | Values |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min. | Typ. | Max. |  |
| DC blocking voltage | $V_{D C}$ | $\mathrm{I}_{\mathrm{R}}=0.12 \mathrm{~mA}$ | 600 | - | - | V |
| Forward voltage | $V_{F}$ | $\mathrm{I}_{\mathrm{F}}=6 \mathrm{~A}, \mathrm{Tj}=25^{\circ} \mathrm{C}$ | - | 1.35 | 1.55 | V |
|  |  | $\mathrm{l}_{\mathrm{F}}=6 \mathrm{~A}, \mathrm{Tj}=150^{\circ} \mathrm{C}$ | - | 1.55 | - | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=6 \mathrm{~A}, \mathrm{Tj}=175^{\circ} \mathrm{C}$ | - | 1.63 | - | V |
| Reverse current | $I_{R}$ | $\mathrm{V}_{\mathrm{R}}=600 \mathrm{~V}, \mathrm{Tj}=25^{\circ} \mathrm{C}$ | - | 1.2 | 120 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\mathrm{R}}=600 \mathrm{~V}, \mathrm{Tj}=150^{\circ} \mathrm{C}$ | - | 18 | - | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\mathrm{R}}=600 \mathrm{~V}, \mathrm{Tj}=175^{\circ} \mathrm{C}$ | - | 42 | - | $\mu \mathrm{A}$ |
| Total capacitance | C | $\mathrm{V}_{\mathrm{R}}=1 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | - | 219 | - | pF |
|  |  | $\mathrm{V}_{\mathrm{R}}=600 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | - | 22 | - | pF |
| Total capacitive charge | Qc | $\mathrm{V}_{\mathrm{R}}=400 \mathrm{~V}, \mathrm{di} / \mathrm{dt}=350 \mathrm{~A} / \mu \mathrm{s}$ | - | 9 | - | nC |
| Switching time | tc | $\mathrm{V}_{\mathrm{R}}=400 \mathrm{~V}, \mathrm{di} / \mathrm{dt}=350 \mathrm{~A} / \mu \mathrm{s}$ | - | 12 | - | ns |

- Thermal characteristics

| Parameter | Symbol | Conditions | Values |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min. | Typ. | Max. |  |
| Thermal resistance | $\mathrm{R}_{\mathrm{th}(\mathrm{c} \text { ( })}$ | - | - | 2.6 | 2.9 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## - Electrical characteristic curves

Fig. $1 V_{F}-I_{F}$ Characteristics


Fig. $3 \mathrm{~V}_{\mathrm{R}}-\mathrm{I}_{\mathrm{R}}$ Characteristics


Fig. $2 \mathrm{~V}_{\mathrm{F}}-\mathrm{I}_{\mathrm{F}}$ Characteristics


Fig. $4 \mathrm{~V}_{\mathrm{R}}$-Ct Characteristics


## - Electrical characteristic curves

Fig. 5 Thermal Resistance vs. Pulse Width


Fig. 7 Ip -Tc Derating Curve


Case Temperature : Tc $\left[{ }^{\circ} \mathrm{C}\right]$

Fig. 6 Power Dissipation


Fig. 8 Io-Pf Characteristics

-Dimensions (Unit : mm)

TO-220AC


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